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Ab initio calculations of the hydroxyl impurities in BaF₂

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ABSTRACT

OH $^-$ impurities in BaF $_2$ crystal have been studied by using density functional theory (DFT) with hybrid exchange potentials, namely DFT-B3PW. Three different configurations of OH $^-$ impurities were investigated and the (111)-oriented OH $^-$ configuration is the most stable one. Our calculations show that OH $^-$ as an atomic group has a steady geometrical structure instead of electronic properties in different materials. The studies on band structures and density of states (DOS) of the OH $^-$ -impurity systems indicate that there are two defect levels induced by OH $^-$ impurities. The two superposed occupied OH $^-$ -bands located 1.95 eV above the valance bands (VB) at Γ point mainly consist of the O p orbitals, and the H s orbitals do the major contribution to the empty defect level located 0.78 eV below the conduction bands (CB). The optical absorption due to the doped OH $^-$ is centered around 8.61 eV.

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1. Introduction

Alkaline-earth fluorides such as CaF₂ and BaF₂, whose band gaps are larger than 10 eV, are very important for many optical applications. As an example, a recent demand for lens materials available in short wavelength lithography is a typical application. The currently targeted wavelength is 157 nm (about 8 eV) from an F₂-excimer laser. This wavelength is far shorter than the transparent region of quartz that is the most popular optical material in the ultraviolet (UV) region, Additionally, for BaF2, it is the fastest luminescent material that has been found to date [1]. Recently, BaF₂ has also been found to exhibit superionic conductivity by dissolving appropriate impurities into the lattice or by introducing an interface that causes the redistribution of ions in the space charge region, and is therefore considered as a candidate material for high-temperature batteries, fuel cells, chemical filters and sensors [2]. Considering the high technological importance of alkalinefluorides, it is not surprising that during the last years, they have been the subject of many experimental and theoretical studies [3-27].

It is well known that optical and mechanical properties of crystals are strongly affected by defects and impurities unavoidably present in any real material. Contemporary knowledge of defects in solids has helped to create a field of technology, namely defect engineering, which is aimed at manipulating the nature and concentration of defects in a material so as to tune its properties in a desired manner or to generate different behaviors. BaF₂ could become important optical materials if one could avoid or, at least, control the photoinduced defect formation, which so far in applications degrades its optical quality. Therefore, it is significative to understand the nature of defects in BaF₂.

Coloration effects in alkaline-earth fluorides are strongly influenced by some impurities. Investigations by Adler and Kveta [28] and Bontinck [29] show that alkaline-earth fluorides reacts readily with water vapor at high temperatures and suggest that the resulting hydrolysis gives rise to a variety of defects which includes O^{2-} ions in fluorine sites and charge-compensating fluorine vacancies, hydrogen impurities dissolved as H_s^- ions in fluorine sites and as H_s^0 in interstitial sites, as well as OH^- impurities. One of the big unsolved problems in the context of the application of alkalineearth fluorides as optical materials is these contaminations in the crystals. As an extension of our previous studies dealing with oxygen and hydrogen impurities in BaF_2 , we performed calculations for OH^- impurities in BaF_2 crystal.

2. Calculation method

It is well known that the HF method considerably overestimates the optical band gap and density functional theory (DFT)

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underestimates it. To study the hydroxyl (OH⁻) impurities in BaF₂ crystal, we applied the first-principles hybrid DFT-B3PW method, according to our previous studies dealing with CaF2, BaF2 and SrF₂ perfect crystals, which gave the best agreement with experiments for the lattice constants, bulk modulus and optical band gaps. The hybrid exchange-correlation B3PW functional involves a hybrid of nonlocal Fock exact exchange, local density approximation (LDA) exchange, and Becke's gradient-corrected exchange functional [30] combined with the nonlocal gradient-corrected correlation potential by Perdew and Wang [31-33]. All numerical calculations on OH⁻ impurities in BaF₂ crystal were performed by the CRYSTAL-2006 computer code [34]. The CRYSTAL-2006 code employs Gaussian-type functions (GTF) localized at atoms as the basis for an expansion of the crystalline orbitals. In order to employ the LCAO-GTF (linear combination of atomic orbitals) method, it is desirable to have optimized basis sets (BS). In our calculations for fluorine atoms, we applied the basis set developed by Catti et al. [5]. For Ba, the BS optimization for BaTiO₃ perovskite was developed and discussed in [35,36]. The Hay-Wadt small-core effective core pseudopotential (ECP) was adopted for the Ba atom [37]. The small-core ECP replaces only inner core or bitals, but orbitals for subvalence electrons as well as for valence electrons are calculated self-consistently. In this paper, we used this BS for Ba. The hydroxyl consists of an oxygen atom and a hydrogen atom. In our calculations, the BS for O given in the Basis Sets Library [34] and for H developed by Dovesi et al. [38] were adopted. The basis sets are believed to be transferable, so that, once determined for some chemical constituents, they may be applied successfully in calculations for a variety of chemical substances where the latter participates.

The reciprocal space integration was performed by sampling the Brillouin zone of the 96-atom supercell with $4 \times 4 \times 4$ Pack–Monkhorst net [39]. The thresholds N (i.e., the calculation of integrals with an accuracy of 10^{-N}) in our calculations were chosen as a compromise between the accuracy of calculations and the large computational time for large supercells. They are 7, 7, 7, 7 and 14 for the Coulomb overlap, Coulomb penetration, exchange overlap, the first-exchange pseudo-overlap and the second-exchange pseudo-overlap, respectively [40]. For the lattice constant (a_0) of BaF₂, we used our theoretical optimized value of 6.26 Å.

To simulate OH^- impurities in BaF_2 , we replaced one fluorine atom with an oxygen atom and inserted a hydrogen atom into an atomic interstitial site near the oxygen. After the fluorine atom is substituted by the OH^- , the atomic configuration of the OH^- and surrounding atoms are re-optimized via a search of the total energy minimum as a function of the atomic displacements from the regular lattice sites.

3. Results and discussion

Firstly, we performed calculations of different configurations for the OH⁻ impurities in BaF₂ crystals. Considering the symmetry of alkaline-earth fluorides, we calculated three simple configurations in which the OH⁻ orients along the (100) or (111) direction. The (100)-oriented OH^- is labeled $OH_{(100)}$ in this paper. For the (111)-oriented case, there are two configurations named OH₍₁₁₁₎ (see Fig. 1) and $HO_{(111)}$. It is clear that the different orders of the oxygen and hydrogen atoms along the (111) direction correspond to the different OH⁻ configurations in BaF₂ crystals, as we can see Fig. 1. According to our calculations, we found that the energetically most favorable configuration of the OH- impurity is Config $OH_{(111)}$, and the total energies of Configs $HO_{(111)}$ and $OH_{(100)}$ are larger than that of Config $OH_{(111)}$ by around 0.38 eV and 0.20 eV, respectively. We also simulated some other configurations with orientations slightly diverging the (111) axis and the results show that these configurations converge to Config OH₍₁₁₁₎ after

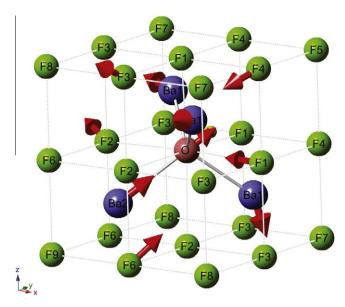


Fig. 1. A view of the OH^- oriented along the (111) axis for the $OH_{(1111)}$ configuration. The arrows show the directions of the atomic displacements surrounding the OH^- impurity. According to the symmetries of the atoms, different labels are defined in spheres.

geometrical relaxations via a search of the minimum total energy. Therefore, we mainly focus our current discussion on Config $OH_{(111)}$.

Next, we computed the geometrical property of OH- and relaxation of atoms surrounding the OH⁻ impurity. The distances between the oxygen and hydrogen (or named the length of the OH^{-}) are 0.97 Å, 0.96 Å and 0.96 Å for Configs $OH_{(111)}$, $HO_{(111)}$ and OH₍₁₀₀₎, respectively. According to our calculations on H₂O molecule, Ca (OH)₂ and Ba (OH)₂ crystals, the lengths of OH⁻ are all around 0.96-0.97 Å, indicating that the OH- has a steady geometrical structure in different materials. The calculation of the OH⁻ position in the BaF₂ bulk shows that one fluorine is substituted by an oxygen and a hydrogen occupies a neighbor interstitial site. For the (111)-oriented OH-, the oxygen atom moves from the regular anion site backwards the neighbor barium along the (111) direction by 1.72% and 6.57% of a_0 for Configs $OH_{(111)}$ (see Fig. 1) and $HO_{(111)}$ respectively. The oxygen in Config OH₍₁₀₀₎ moves slightly along the (100) direction by less than 1% of a_0 . The calculated atomic displacements of the OH $^-$ and surrounding atoms for Config $OH_{(111)}$ are listed in Table 1. The three Ba1 atoms are repulsed from the OH $^-$ by around 0.97% of a_0 and the Ba2 moves towards the OH⁻ by 0.84% of a_0 . The relaxations of neighbor fluorine atoms are slight and less than 0.5% of a_0 .

Table 1 Atomic relaxations (D (% a_0): as a percentage of the lattice constant: 6.26 Å) and effective charges (Q (e)) of the OH⁻ and surrounding atoms in the BaF₂ 96-atom supercell for Config OH₍₁₁₁₎. Δ Q(e) is the charge difference between the defective and perfect crystals (Q_{ba} = +1.845e, Q_F = -0.923e in perfect BaF₂). The shell labels have been defined in Fig. 1.

Atoms (shell)	Number	D (%a ₀)	Q (e)	$\Delta Q\left(e\right)$
0	1	1.72	-1.033	
Н	1	_	+0.241	_
Ba1	3	0.97	+1.819	-0.026
Ba2	1	0.84	+1.840	-0.005
F1	3	0.20	-0.931	-0.008
F2	3	0.19	-0.928	-0.005
F3	6	0.32	-0.923	0
F4	3	0.22	-0.924	-0.001
F6	3	0.21	-0.923	0

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